



STPAC01F1

IPAD™

RF DETECTOR FOR POWER AMPLIFIER CONTROL

MAIN PRODUCT CHARACTERISTICS

The STPAC01F1 has two outputs, one for the signal detection and another one for the temperature compensation:

- $V_{DCout} = 0.88 \text{ V}$ at 0.85 GHz at 10 dBm
- $V_{DCout} = 1.07 \text{ V}$ at 1.85 GHz at 10 dBm
- $V_{supply} = 5 \text{ V max.}$

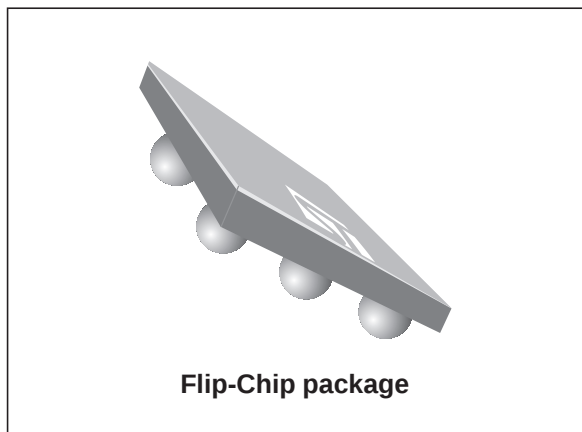
DESCRIPTION

The STPAC01 is an integrated RF detector for the power control stage. It converts RF signal coming from the coupler into a DC signal usable by the digital stage. It is based on the use of two similar diodes, one providing the signal detection while the second one is used to provide a temperature information to thermal compensation stage. A biasing stage suppresses the detection diode drop voltage effect.

Target applications are cellular phones and PDA using GSM, DCS, PCS, AMPS, TDMA, CDMA and 800MHz to 1900MHz frequency ranges

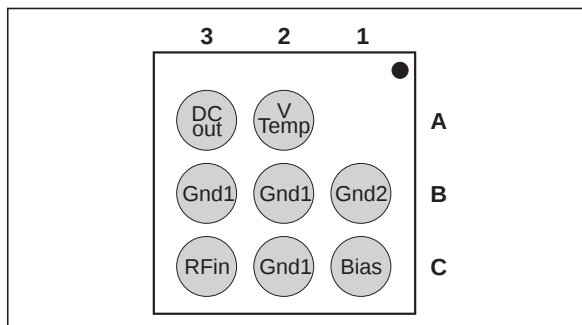
BENEFITS

- The use of IPAD technology allows the RF front-end designer to save PCB area and to drastically suppress parasitic inductances.

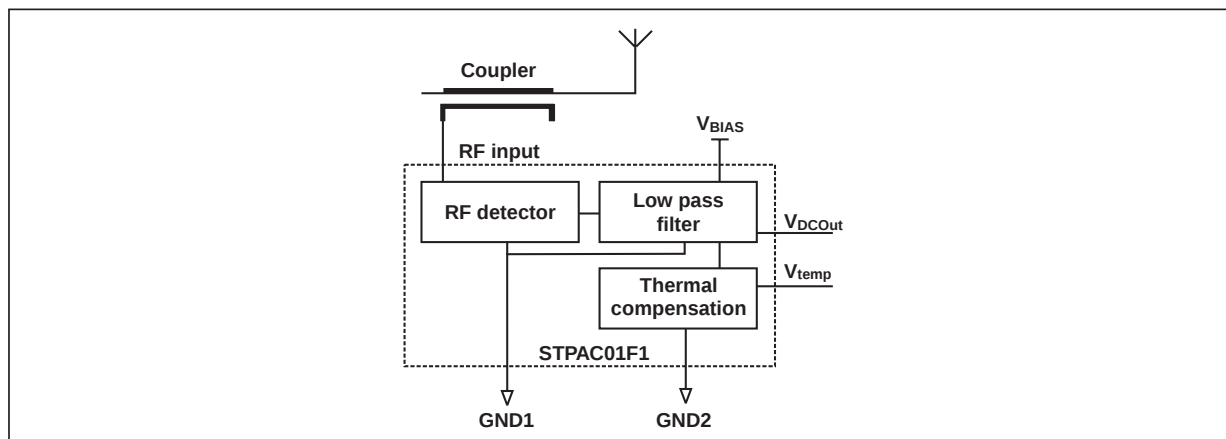


Flip-Chip package

PIN CONFIGURATION (ball side)



FUNCTIONAL DIAGRAM



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STPAC01F1

ABSOLUTE RATINGS (T_{amb} = 25°C)

Symbol	Parameter and test conditions	Value	Unit
V _{BIAS}	Bias voltage	5	V
P _{RF}	RF power at the RF input	20	dBm
F _{OP}	Operating frequency range	0.8 to 2	GHz
V _{PP}	ESD level as per MIL-STD 883E method 3015.7 notice 8 (HBM)	100	V
T _{OP}	Operating temperature range	-30 to +85	°C
T _{STG}	Storage temperature range	-55 to 150	°C

ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C)

PARAMETERS RELATED TO BIAS VOLTAGE

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _{BIAS}	Operating bias voltage		2.2		3.2	V
I _{BIAS}	Bias current	V _{BIAS} = 3.2 V			0.5	mA

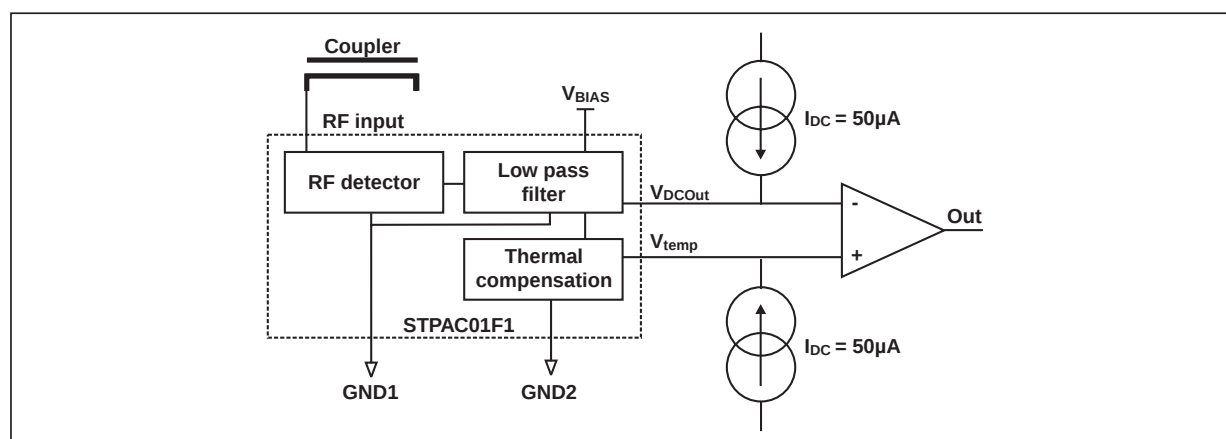
PARAMETERS RELATED TO DETECTION FUNCTION (V_{BIAS} = 2.7 V, DC output load = 100 kΩ)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _{DCout}	DC output voltage (see fig. 1, I _{DC} = 50μA)	F = 1.85 GHz, P _{RF} = 10 dBm	0.97	1.07	1.17	V
		F = 1.85 GHz, P _{RF} = -20 dBm	1.83	1.93	2.03	
		F = 0.85 GHz, P _{RF} = 10 dBm	0.78	0.88	0.98	
		F = 0.85 GHz, P _{RF} = -20 dBm	1.83	1.93	2.03	
ΔV _{DCout}	DC output voltage variation (see fig. 5, I _{DC} = 50μA)	0 < T _{amb} < 70°C, F = 1.85 GHz, P _{RF} = 10 dBm		0.09		V
		2.2 < V _{BIAS} < 3.2 V, F = 1.85 GHz, P _{RF} = 10 dBm		0.44		

PARAMETERS RELATED TO TEMPERATURE FUNCTION

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _{Temp}	Temperature output voltage (see fig. 6)	I _{DC} = 50μA	1.83	1.93	2.03	V
ΔV _{Temp}	Temperature output voltage variation (see fig. 6)	I _{DC} = 50μA, 0 < T _{amb} < 70 °C		0.09		V
		I _{DC} = 50μA, 2.2 < V _{BIAS} < 3.2 V		0.44		

APPLICATION DIAGRAM



The STPAC01 is the first part of the power amplifier stage and provides both RF power and die temperature measurements. The above figure gives the basic circuit of RF detector.

A coupler located on the line between RF amplifier output and the antenna takes a part of the available power and applies it to STPAC01 RF input.

The RF detector and the low pass filter provide a DC voltage depending on the input power. Thermal compensation provides a DC voltage depending on the ambient temperature. As the detection system and the thermal compensation are based on the same topology, V_{DCout} will have the same temperature variation as V_{temp} . Connected to a differential amplifier, the output will be a voltage directly linked to the RF input power. V_{DCout} and V_{temp} must be bias with $50\mu A$ DC current.

This topology offers the most accurate output value as it is 100% compensated.

Fig. 1: V_{DCout} measurement circuit.

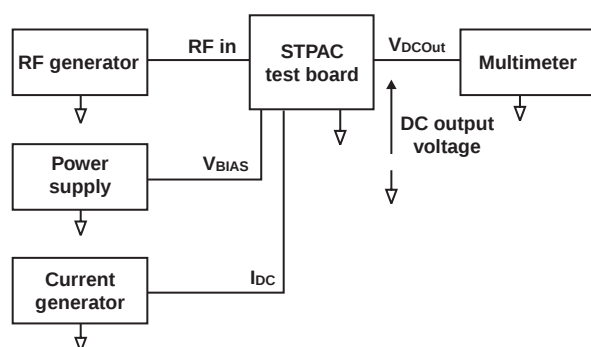


Fig. 2: V_{DCout} versus RF input power.

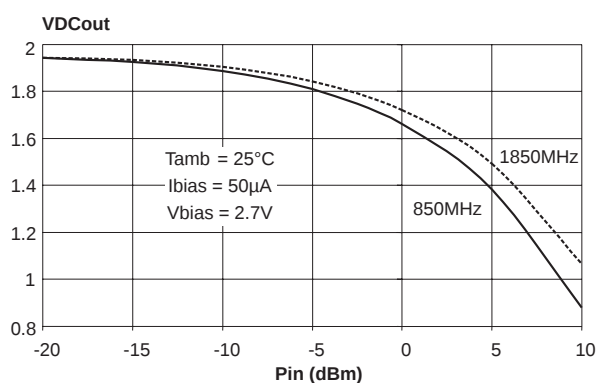


Fig. 3: Relative variation of V_{DCout} versus frequency (from 800 to 900 MHz).

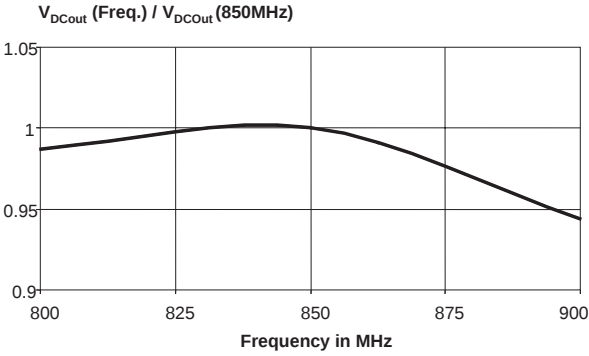


Fig. 4: Relative variation of V_{DCout} versus frequency (from 1800 to 1900 MHz).

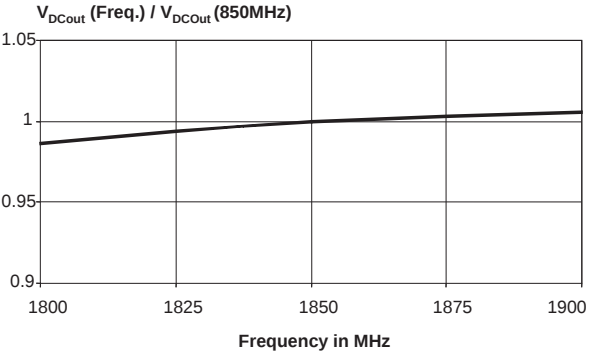


Fig. 5: Temperature effect measurement circuit on V_{DCout} .

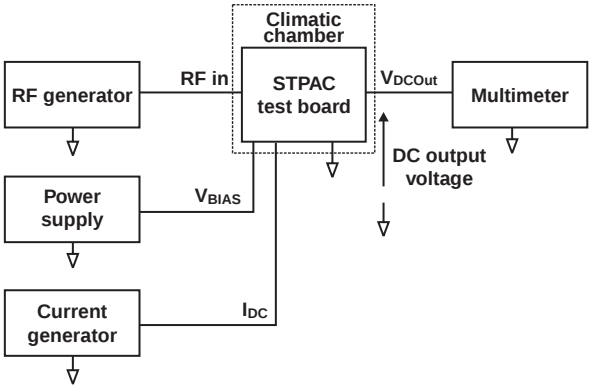


Fig. 6: V_{temp} measurement circuit.

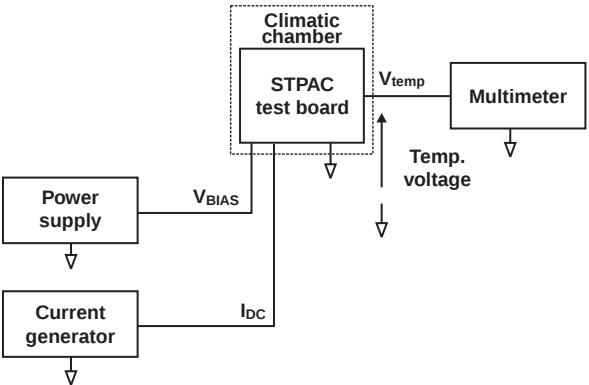
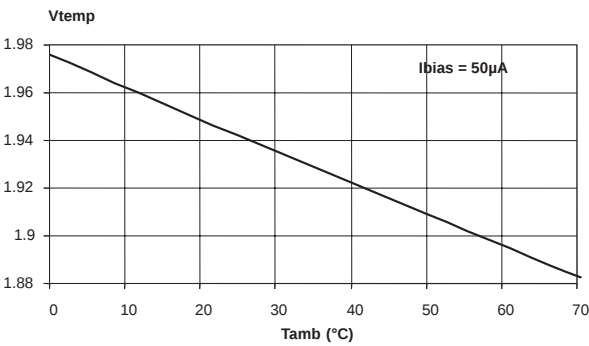
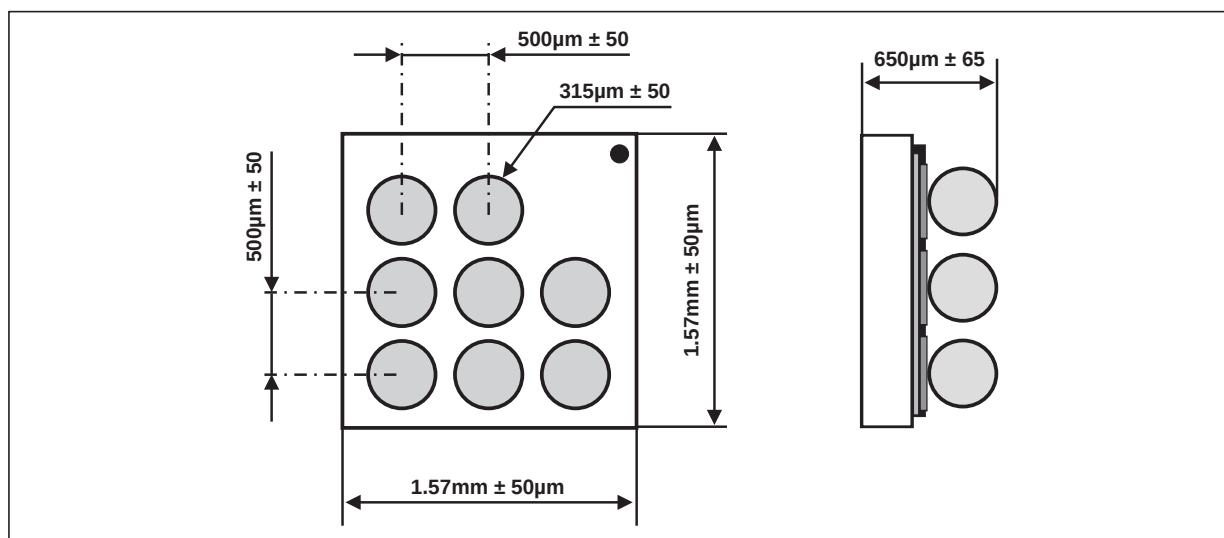


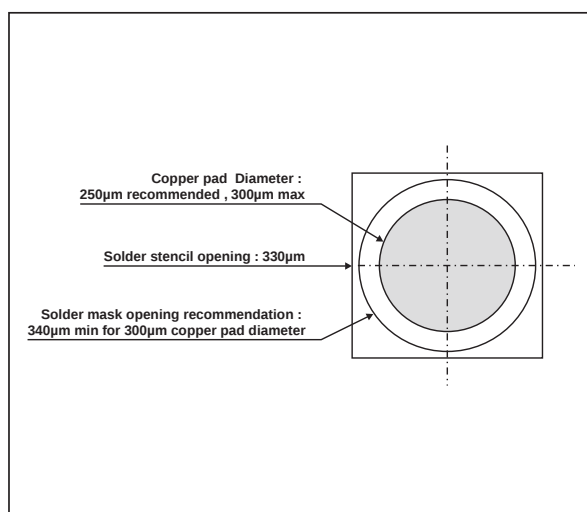
Fig. 7: V_{temp} output voltage versus ambient temperature.



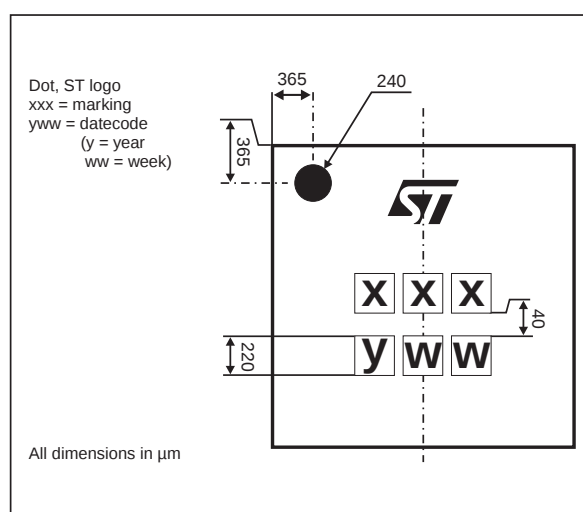
PACKAGE MECHANICAL DATA



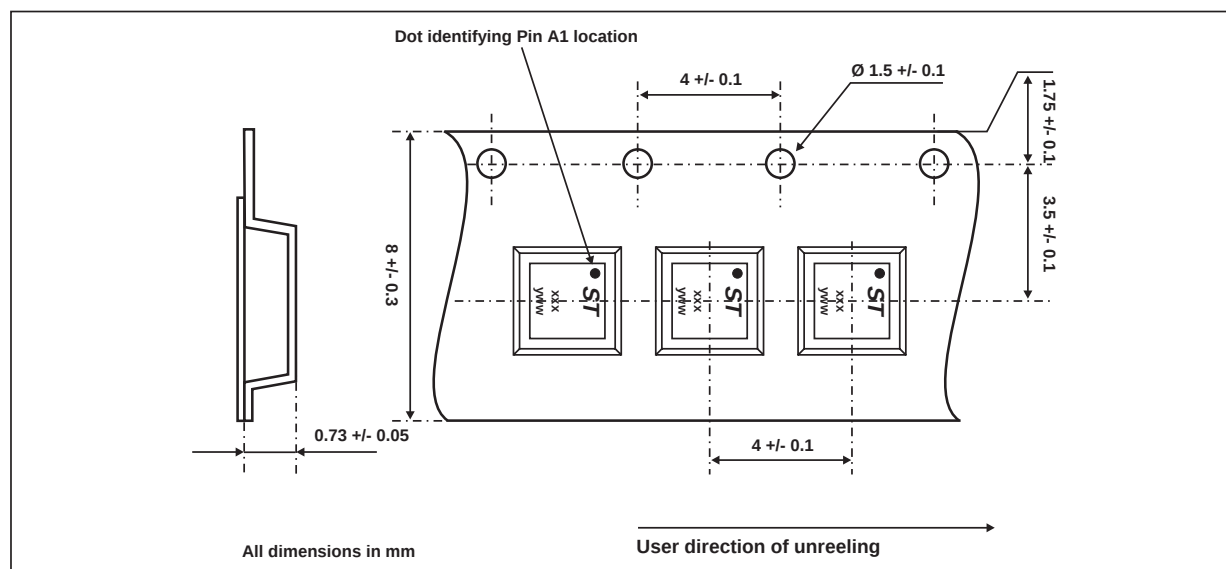
FOOT PRINT RECOMMENDATIONS



MARKING



FLIP-CHIP TAPE AND REEL SPECIFICATION



OTHER INFORMATION

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STPAC01F1	RAT	Flip-Chip	3.3 mg	5000	Tape & reel

Note: More packing informations are available in the application note AN1235: "Flip-Chip: Package description and recommendations for use"

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- Техническая поддержка проекта;
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